Enhanced electrical resistivity before N eel order in the m etals, $R C uA s_2$ (R = Sm, Gd, T b and D y)

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W e report an unusual temperature (T) dependent electrical resistivity () behavior in a class of termary interm etablic compounds of the type RCuAs₂ (R = Rare-earths). For some rare-earths (Sm, Gd, Tb and Dy) with negligible 4f-hybridization, there is a pronounced minimum in (T) far above respective Neel temperatures (T_N). However, for the rare-earths which are more prone to exhibit such a (T) minimum due to 4f-covalent mixing and the K ondo e ect, this minimum is depressed. These ndings, di cult to explain within the hither-to-known concepts, present an interesting scenario in magnetism.

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It is a fundam ental fact in condensed matter physics that, in metals containing magnetic moments, the spindisorder contribution to electrical resistivity () in the param agnetic state is a constant adding to the lattice contribution, which decreases with decreasing temperature (T). Naturally, usually exhibits a positive Tcoe cient down to the magnetic ordering temperature (T_{o}) , except perhaps a weak critical point e ect restricted to a narrow T-range (less than few percent of Curie tem perature).¹ However, in the event that the sign of the exchange interaction between the local magnetic m om ent and the conduction electrons is negative (the phenom enon called "the K ondo e ect") due to covalent m ixing of the relevant orbital, can show a low T-uptum increasing logarithm ically below a characteristic tem perature leading to a minimum in (T) well above T_{o} . This aspect has been very well known for Ce and Yb alloys. Here, we report that, in a class of ternary interm etallic com pounds of the type RCuAs₂ (R = rare-earths),³ the rare-earths with strictly localized 4f character (in which case one does not anticipate the K ondo e ect, e.g., Sm , Gd, Tb and Dy) exhibit a pronounced m in im um in (T) above respective N eeltem peratures (T $_{\rm N}$). However, for R = Pr, Nd and even Yb, no such m in im um is observed in

(T). These ndings present an unusual and interesting scenario as far as electronic transport in m agnetic m etals is concerned.

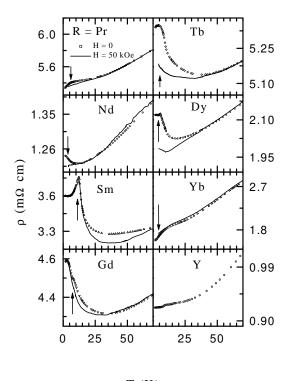
The series of compounds under investigation, $RCuAs_2$ (R = Pr, Nd, Sm, Gd, Tb, Dy, Yb, and Y) crystallize in the HfC uSiz-type layered tetragonal form (space group, P 4/nmm)³ and the polycrystalline m aterials in the single phase form were synthesized as described in Ref. 3. The

m easurem ents (1.8 – 300 K) in zero m agnetic eld (H) as wellas in the presence of a H of 50 kO ewere perform ed on rectangular-shaped specim ens (9m m X 2m m X 2m m) by a four-probe m ethod employing spring-baded pressure contacts with a typical spacing of 2m m between voltage leads. The sharp tip (diam eter < 0.2m m) attached to the springs enables us to m inim ise the errors in arising due to uncertainties in the m easurem ent of spacing between voltage leads. In order to arrive at the T_N values, we have also carried out dc m agnetization (M) (employing a commercial m agnetom eter) and heat-capacity (C) m easurem ents.

Figure 1 shows (T) behavior for all the compounds below 70 K. Let us rst look at the data for R = Sm, G d, T b and D y, in which the 4f orbitals are known to be so deeply localized that the covalent m ixing e ects can be ignored. The value of falls in the m illi-ohm s range around 300 K in all cases. How ever, since the sam ples are found to be porous, the m easured absolute values of

are overestim ated and hence should not be taken too seriously. W hat is in portant to note is that decreases m onotonically with T without any other feature down to 70 K (and hence not shown here). This establishes that all these compounds behave like metals. As the T is low ered, one nds that, in these com pounds, attains surprisingly a prominent minimum at a tem perature, $T_{m in}$ (= about 35 K for Sm, Gd and Tb; about 20 K for Dy), below which it rises again. It should be noted that this feature is not observed for the Y com pound (as well as for R = Lu, not shown here), in which case (T) exhibits norm ally expected m etallic behaviour down to the m easured lowest temperature (apart from a weak drop at about 7 K, which is presum ably due to traces of a parasitic superconducting phase). This observation indicates that the m in im um in other cases is magnetic in origin.

In order to rule out the origin of this uptum from m agnetic superzone form ation⁴ due to possible antiferrom agnetic ordering at $T_{\rm m\ in}$, it is important to make sure from independent m easurements that $T_{\rm N}$ falls well below $T_{\rm m\ in}$. In this respect, the dc m agnetic susceptibility () and C data shown in Figs. 2 and 3 are quite conclusive. The above about 100 K is found to follow C unie-W eiss behavior (not shown here) and the elective m om ents ($_{\rm eff}$) obtained from this temperature range



T (K)

FIG.1. Electrical resistivity behaviour of RCuAs $_2 \mod p$ pounds below 70 K in zero magnetic eld as well as in the presence of 50 kO e. Vertical arrows mark the Neeltem peratures.

are in full agreem ent with that expected for respective trivalent R ions ($_{eff}$) = 0.7, 7.9, 9.7, and 10.63 $_{B}$) for R = Sm , G d, T b and D y respectively). The features due to magnetic ordering appear as a well-de ned peak in and C and/or as a sudden change in the slope of inverse

versus T well below ${\tt T}_{\tt m\ in}$ as one lowers the T. The $T_{\rm N}\,$ thus obtained are close to 12.5, 9, 9 and 8 K for Sm , Gd, Tb and Dy cases respectively. (There are additional features at further lower tem peratures, which could be due to spin-reorientation e ects. As this is not pertinent to the main conclusion of this article, we will not discuss this aspect further). There could be a sm all am biguity in precisely locating T_N from the C data, as the peak-positions can be shifted to a lower T or the C-tail m ay continue to a higher T, depending on the com plexities of the magnetic structure.⁵ But the fact remains that the features due to the onset of magnetic transition appear well below $T_{m in}$ in all cases. Therefore, the minimum in (T) well above 12 K can not be attributed to magnetic superzone gap formation. (increases further below T_N in some cases, rather than exhibiting a drop due to the loss of spin-disorder contribution, which m ay be attributed to this gap e ect). It m ay be stated that for both the eld-cooled and the zero-cooled conditions of the specim ens are essentially the same, which establishes that there is no spin-glass freezing⁶ in the T range of investigation. Isotherm alM in the magnetically

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ordered state, m easured till H = 120 kO e (see Fig. 2, bottom, for instance for the data at 1.6 K), varies sluggishly with H without any hysteresis; in fact for R = Sm and G d, M varies linearly with H, whereas Tb and Dy exhibit m etam agnetic-like features. These establish that the m agnetic ordering is indeed of an antiferrom agnetictype and not of a ferrom agnetic-type.

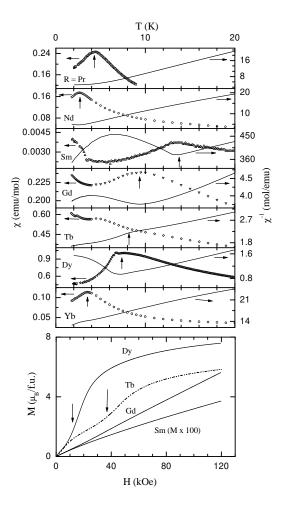


FIG.2. (Top) M agnetic susceptibility m easured in a m agnetic eld of 100 O e (circles) and inverse susceptibility m easured in a eld of 5 kO e (lines) for RC uA s_2 com pounds. Vertical arrow s m ark the N eel tem peratures. (B ottom) Isotherm al m agnetization behavior for R = Sm , G d, T b and D y at 1.6 K with the arrows showing the eld around which there is an upw ard curvature in som e cases and the plots are found to be non-hysteretic.

It may be recalled that we have earlier reported a similar behavior for som eGd system s, e.g., Gd_2PdSi_3 , crystallizing in a A \mathbb{B}_2 -derived temary hexagonal structure, but other rare-earth members of those series do not exhibit such a minimum in (T). The present series of compounds is thus unique in the sense that the observation of min spans over the entire rare-earth series (but not restricted to Gd alone). It is this noting that provides compelling evidence for a more-common hither-to-

unrecognised magnetism-related electron scattering effects in the param agnetic state. There is also another noteworthy di erence between these two classes of com pounds: The minimum is very sensitive to the presence of an external H in the case of Gd_2PdSi_3 , whereas the application of a H of 50 kO e does not depress this m inim a in the present compounds, most notably for R = G dand Sm (see Fig. 1). In other words, the magnetoresistance (MR = [(H) - (0)]/((0)) is quite sm all varying sluggishly with H; this also rules out any explanation in terms of possible grain boundary e ects at least for R = Sm and Gd, as any extra scattering from the magnetic ions at the grain boundaries have been in general known to be strongly suppressed by small applications of H. Thus, for H = 50 kOe, the magnitude of MR in the T-region of interest is much less than or close to 2%, which could be compared with the net increase (about 14%, 6%, 4% and 4% for R = Sm, Gd, Tb and Dy respectively) of zero-eld as measured at T_N relative to that at $T_{\,m\,\,in}$. Though sm aller in magnitude, there is a noticeable in uence of H for R = Tb and Dy. Possibly, there is a subtle di erence in the origin of (T) m inimum between the present G d and Sm compounds on the one hand and Gd_2PdSi_3 on the other with Tb and Dy com pounds lying som ew here between these two lim its.

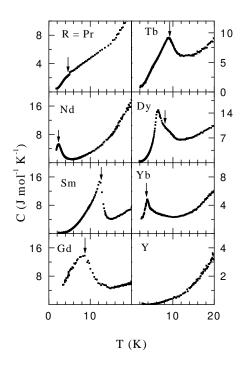


FIG.3. Heat-capacity as a function of temperature for $RCuAs_2$ compounds. Vertical arrows mark the Neel temperatures, as inferred from the magnetic susceptibility data.

In order to explore whether the uptum in below T_{m in} in the param agnetic state could be understood in term s of hither-to-known concepts, we plot the data in the range 12.5 to 31 K (region of interest) in various ways in Fig. 4, for instance, for Sm CuAs₂. Clearly, the uptum cannot be attributed to the K ondo e ect due to deeply localized nature of the 4f orbital. Though, occasionally, Sm compounds show the K ondo e $ect_{,}^{2}$ this phenom enon can not be expected for Gd, Tb and Dy. The absence of the Kondo e ect even in this Sm com pound is further supported by the non-logarithm ic variation of (Fig. 4d). To substantiate this further, we have obtained the 4f contribution ($_{4f}$) to by subtracting the lattice part from the know ledge of (T) of the Y analogue. W e would like to emphasize that the slopes of (T) plots for these two com pounds are found to be the sam e at room temperature, which implies that no further correction as described by Cattaneo and W ohlleben⁸ needs to be carried out to obtain precise lattice contribution. The $_{4f}$ thus obtained is nearly constant (see Fig. 4) at tem peratures above 100 K (consistent with the constancy of spin-disorder contribution), how ever raising gradually with decreasing T in a non-logarithm ic way. Since all the sam ples were synthesized under identical conditions and the pressure employed to obtain the compacted and sinteted pellets for studies in all sam ples are the sam e, we believe that possible errors in the $_{\rm 4f}$ (T) due to di erences in porosity and consequent grain boundary e ects am ong these sam ples are rather negligible. In addition, we arrive at a similar conclusion even when we employ the data of Lu sample for lattice contribution. The plot of ln () versus 1/T is not linear (Fig. 4c) and the absence of activated behavior rules out the form ation of any type of gap as a possible cause of this uptum. The plots of ln () versus T $^{1=4}$ and T $^{1=2}$ are also not linear (Figs. 4a and b), thereby ruling out an explanation in term s of variable range hopping and C oulom b gap form ation m echanism s.9 Apparently, there is no $T^{1=2}$ dependence of as well (Fig. 4e), which im plies that presently known weak-disorderinduced electron localization ideas discussed by Lee and R am akrishnan¹⁰ are not adequate to describe the anom alies. Another mechanism that could be advanced is in term softhe form ation of magnetic polarons, as proposed for EuSe (Ref. 11), EuB₆ (Ref. 12) and T $\frac{1}{2}$ M n_2 O₇ (Refs. 13-15), but the application of a H is expected to have a pronounced depressing e ect on the -upturn resulting in a large negative MR, in contrast to the observation. For the same reason, the s-f exchange model (considering a strong scattering of 5d conduction electrons by the localized 4felectrons)¹⁶ proposed to explain the large M R behavior of $G dI_2$ m ay not be applicable; additionally, this m odel assum es ferrom agnetic ordering at low tem peratures, whereas the present com pounds are antiferrom agnets; it is not clear whether this model can be modi ed to explain the features. The fact that behavior in Y and Lu analogues is norm al in this regard establishes that the origin of the above anom aly does not lie in the band structure. Thus, there is no straightforw ard explanation

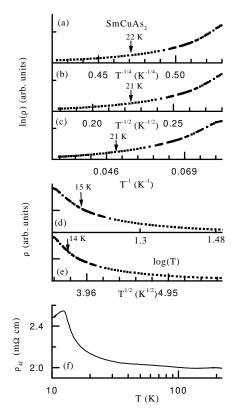


FIG.4. The electrical resistivity in the tem perature range 12.5–31 K plotted in various ways for Sm CuAs_2 compounds. Fig. (f) shows the 4f contribution in the logarithm ic tem perature scale in the T range 10–225 K.

We now inspect the behaviour of Pr, Nd and Yb compounds (Fig. 1) along with the and C behavior (Figs. 2 and 3). PrCuAs₂ exhibits a distinct feature due to antiferrom agnetic ordering at about 4 K, as evidenced by the feature in (though the corresponding anom aly in C is not sharp presum ably due to low entropy of the crystal-eld-split ground state). Nd and Yb com pounds are found to order magnetically close to 2.5 and 4.0 K respectively as marked by the features in C and data. It is worth mentioning that, though the T_N values in this series are in general larger than that expected on the basis of de Gennes scaling, this Y b com pound turns out to be one of the few Yb com pounds exhibiting a high m agnetic ordering tem perature.¹⁷ This makes this Yb com pound interesting in its own right. Following the behaviour in other members of this series described above, one would naively expect that there should be a minimum in the plot of (T) above T_N . However, it is striking to note that no such minimum could be observed for Pr and Y b com pounds and the M R is also negligible; in other words, these com pounds behave in a norm alway in this respect. For the Nd compound, there is a weak upturn below 15 K to the tune of 1% only. W e speculate that, at least for

these cases, the origin of this suppression of m_{in} may lie in non-negligible degree of 4fm ixing, characteristic not only of Yb, but also of Pr and Nd under favorable circum stances, $^{18;19}$ though there could be other controlling factors.²⁰ In the case of Y b com pound, this covalent m ixing manifests itself usually as the K ondo e ect; the observed behavior of (T) plot above T_N is typical of Y b-based K ondo lattices²¹ and the tem perature (around starts falling as T is low ered repre-130 K) at which sents the onset of coherent scattering am ong the K ondo centres.²² The positive sign of MR (see Fig. 1) arising out of destruction of K ondo-coherence by the application of H is consistent with this explanation.²² Therefore, we tend to believe that the K ondo-coherence som ehow suppresses the upturn in as T_N is approached. In the case of Pr and Nd com pounds, the spatial mixing of 4f (see Cooper² and Ref. 19), though does not result in the Kondo e ect, is apparently e ective in depressing m in. It is quite well-known¹⁸ that the strength of 4fhybridization decreases progressively as one moves from Ce to Sm and the observation of a similar trend²³ in $_{m in}$ supports this interpretation, at least for these cases.

To conclude, we report a new class of rare-earth based interm etallic com pounds, RC uA s_2 (R = Sm, Gd, Tb and Dy), with a novel electrical transport behaviour before antiferrom agnetic order. The ndings in ply that the understanding of the electronic transport in the paramagnetic state of relatively sim ple magnetic m etals is far from com plete. We propose that the ideas based on weak localisation¹⁰ m ay have to be extended incorporating strongly enhanced magnetic critical scattering e ects extending over a wide temperature range above T_o.

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- 23 O ur investigations reveal that the Ce compound is dom in nated by the K ondo e ect only in the range 2 300 K .

Enhanced electrical resistivity before Néel order in the metals, $RCuAs_2$ (R= Sm, Gd, Tb and Dy)

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We report an unusual temperature (T) dependent electrical resistivity(ρ) behavior in a class of ternary intermetallic compounds of the type RCuAs₂ (R= Rare-earths). For some rare-earths (Sm, Gd, Tb and Dy) with negligible 4fhybridization, there is a pronounced minimum in $\rho(T)$ far above respective Néel temperatures (T_N). However, for the rare-earths which are more prone to exhibit such a $\rho(T)$ minimum due to 4f-covalent mixing and the Kondo effect, this minimum is depressed. These findings, difficult to explain within the hither-to-known concepts, present an interesting scenario in magnetism.

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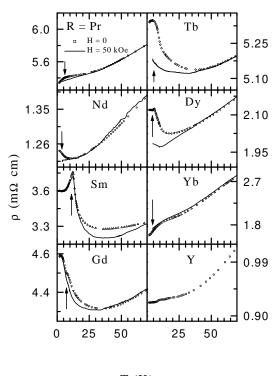
It is a fundamental fact in condensed matter physics that, in metals containing magnetic moments, the spindisorder contribution to electrical resistivity (ρ) in the paramagnetic state is a constant adding to the lattice contribution, which decreases with decreasing temperature (T). Naturally, ρ usually exhibits a positive Tcoefficient down to the magnetic ordering temperature (T_{o}) , except perhaps a weak critical point effect restricted to a narrow T-range (less than few percent of Curie temperature).¹ However, in the event that the sign of the exchange interaction between the local magnetic moment and the conduction electrons is negative (the phenomenon called "the Kondo effect") due to covalent mixing of the relevant orbital, ρ can show a low T-upturn increasing logarithmically below a characteristic temperature leading to a minimum in $\rho(T)$ well above T_{ρ} . This aspect has been very well known for Ce and Yb alloys.² Here, we report that, in a class of ternary intermetallic compounds of the type $RCuAs_2$ (R = rare-earths),³ the rare-earths with strictly localized 4f character (in which case one does not anticipate the Kondo effect, e.g., Sm, Gd, Tb and Dy) exhibit a pronounced minimum in $\rho(T)$ above respective Néel temperatures (T_N) . However, for R = Pr, Nd and even Yb, no such minimum is observed in $\rho(T)$. These findings present an unusual and interesting scenario as far as electronic transport in magnetic metals is concerned.

The series of compounds under investigation, RCuAs₂ (R= Pr, Nd, Sm, Gd, Tb, Dy, Yb, and Y) crystallize in

the HfCuSi₂-type layered tetragonal form (space group, P4/nmm)³ and the polycrystalline materials in the single phase form were synthesized as described in Ref. 3. The ρ measurements (1.8 - 300 K) in zero magnetic field (H) as well as in the presence of a H of 50 kOe were performed on rectangular-shaped specimens (9mm X 2mm X 2mm) by a four-probe method employing spring-loaded pressure contacts with a typical spacing of 2mm between voltage leads. The sharp tip (diameter <0.2mm) attached to the springs enables us to minimise the errors in ρ arising due to uncertainties in the measurement of spacing between voltage leads. In order to arrive at the T_N values, we have also carried out dc magnetization (M) (employing a commercial magnetometer) and heat-capacity (C) measurements.

Figure 1 shows $\rho(T)$ behavior for all the compounds below 70 K. Let us first look at the data for R = Sm, Gd. Tb and Dv. in which the 4f orbitals are known to be so deeply localized that the covalent mixing effects can be ignored. The value of ρ falls in the milli-ohms range around 300 K in all cases. However, since the samples are found to be porous, the measured absolute values of ρ are overestimated and hence should not be taken too seriously. What is important to note is that ρ decreases monotonically with T without any other feature down to 70 K (and hence not shown here). This establishes that all these compounds behave like metals. As the T is lowered, one finds that, in these compounds, ρ attains surprisingly a prominent minimum at a temperature, T_{min} (= about 35 K for Sm, Gd and Tb; about 20 K for Dy), below which it rises again. It should be noted that this feature is not observed for the Y compound (as well as for R = Lu, not shown here), in which case $\rho(T)$ exhibits normally expected metallic behaviour down to the measured lowest temperature (apart from a weak drop at about 7 K, which is presumably due to traces of a parasitic superconducting phase). This observation indicates that the minimum in other cases is magnetic in origin.

In order to rule out the origin of this upturn from magnetic superzone formation⁴ due to possible antiferromagnetic ordering at T_{min} , it is important to make sure from independent measurements that T_N falls well below T_{min} . In this respect, the dc magnetic susceptibility (χ) and C data shown in Figs. 2 and 3 are quite conclusive. The χ above about 100 K is found to follow Curie-Weiss behavior (not shown here) and the effective moments (μ_{eff}) obtained from this temperature range



T (K)

FIG. 1. Electrical resistivity behaviour of $RCuAs_2$ compounds below 70 K in zero magnetic field as well as in the presence of 50 kOe. Vertical arrows mark the Néel temperatures.

are in full agreement with that expected for respective trivalent R ions $(\mu_{eff}) = 0.7, 7.9, 9.7, \text{ and } 10.63 \ \mu_B)$ for R = Sm, Gd, Tb and Dy respectively). The features due to magnetic ordering appear as a well-defined peak in χ and C and/or as a sudden change in the slope of inverse χ versus T well below \mathcal{T}_{min} as one lowers the T. The T_N thus obtained are close to 12.5, 9, 9 and 8 K for Sm, Gd, Tb and Dy cases respectively. (There are additional features at further lower temperatures, which could be due to spin-reorientation effects. As this is not pertinent to the main conclusion of this article, we will not discuss this aspect further). There could be a small ambiguity in precisely locating T_N from the C data, as the peak-positions can be shifted to a lower T or the C-tail may continue to a higher T, depending on the complexities of the magnetic structure.⁵ But the fact remains that the features due to the onset of magnetic transition appear well below T_{min} in all cases. Therefore, the minimum in $\rho(T)$ well above 12 K can not be attributed to magnetic superzone gap formation. (ρ increases further below \mathbf{T}_N in some cases, rather than exhibiting a drop due to the loss of spin-disorder contribution, which may be attributed to this gap effect). It may be stated that χ for both the field-cooled and the zero-cooled conditions of the specimens are essentially the same, which establishes that there is no spin-glass freezing⁶ in the T range of investigation. Isothermal M in the magnetically ordered state, measured till H = 120 kOe (see Fig. 2, bottom, for instance for the data at 1.6 K), varies sluggishly with H without any hysteresis; in fact for R = Sm and Gd, M varies linearly with H, whereas Tb and Dy exhibit metamagnetic-like features. These establish that the magnetic ordering is indeed of an antiferromagnetictype and not of a ferromagnetic-type.

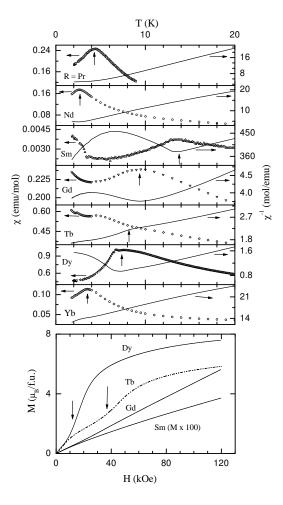


FIG. 2. (Top) Magnetic susceptibility measured in a magnetic field of 100 Oe (circles) and inverse susceptibility measured in a field of 5 kOe (lines) for RCuAs₂ compounds. Vertical arrows mark the Néel temperatures. (Bottom) Isothermal magnetization behavior for R= Sm, Gd, Tb and Dy at 1.6 K with the arrows showing the field around which there is an upward curvature in some cases and the plots are found to be non-hysteretic.

It may be recalled that we have earlier reported a similar ρ behavior for some Gd systems, e.g., Gd₂PdSi₃, crystallizing in a AlB₂-derived ternary hexagonal structure,⁷ but other rare-earth members of those series do not exhibit such a minimum in $\rho(T)$. The present series of compounds is thus unique in the sense that the observation of ρ_{min} spans over the entire rare-earth series (but not restricted to Gd alone). It is this finding that provides compelling evidence for a more-common hither-tounrecognised magnetism-related electron scattering effects in the paramagnetic state. There is also another noteworthy difference between these two classes of compounds: The minimum is very sensitive to the presence of an external H in the case of Gd₂PdSi₃, whereas the application of a H of 50 kOe does not depress this minima in the present compounds, most notably for R = Gdand Sm (see Fig. 1). In other words, the magnetoresistance (MR = $[\rho(H) - \rho(0)] / \rho(0)$) is quite small varying sluggishly with H; this also rules out any explanation in terms of possible grain boundary effects at least for R = Sm and Gd, as any extra scattering from the magnetic ions at the grain boundaries have been in general known to be strongly suppressed by small applications of H. Thus, for H = 50 kOe, the magnitude of MR in the T-region of interest is much less than or close to 2%, which could be compared with the net increase (about 14%, 6%, 4% and 4% for R = Sm, Gd, Tb and Dy respectively) of zero-field ρ as measured at T_N relative to that at T_{min} . Though smaller in magnitude, there is a noticeable influence of H for R = Tb and Dy. Possibly, there is a subtle difference in the origin of $\rho(T)$ minimum between the present Gd and Sm compounds on the one hand and Gd_2PdSi_3 on the other with Tb and Dy compounds lying somewhere between these two limits.

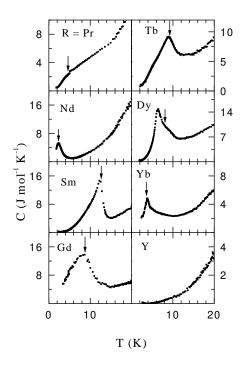


FIG. 3. Heat-capacity as a function of temperature for $RCuAs_2$ compounds. Vertical arrows mark the Néel temperatures, as inferred from the magnetic susceptibility data.

In order to explore whether the upturn in ρ below T_{min} in the paramagnetic state could be understood in terms of hither-to-known concepts, we plot the data in the range 12.5 to 31 K (region of interest) in various ways in Fig. 4, for instance, for SmCuAs₂. Clearly, the upturn cannot be attributed to the Kondo effect due to deeply localized nature of the 4f orbital. Though, occasionally, Sm compounds show the Kondo effect,² this phenomenon can not be expected for Gd. Tb and Dv. The absence of the Kondo effect even in this Sm compound is further supported by the non-logarithmic variation of ρ (Fig. 4d). To substantiate this further, we have obtained the 4f contribution (ρ_{4f}) to ρ by subtracting the lattice part from the knowledge of $\rho(T)$ of the Y analogue. We would like to emphasize that the slopes of $\rho(T)$ plots for these two compounds are found to be the same at room temperature, which implies that no further correction as described by Cattaneo and Wohlleben⁸ needs to be carried out to obtain precise lattice contribution. The ρ_{4f} thus obtained is nearly constant (see Fig. 4) at temperatures above 100 K (consistent with the constancy of spin-disorder contribution), however raising gradually with decreasing T in a non-logarithmic way. Since all the samples were synthesized under identical conditions and the pressure employed to obtain the compacted and sinteted pellets for ρ studies in all samples are the same, we believe that possible errors in the $\rho_{4f}(T)$ due to differences in porosity and consequent grain boundary effects among these samples are rather negligible. In addition, we arrive at a similar conclusion even when we employ the data of Lu sample for lattice contribution. The plot of $\ln(\rho)$ versus 1/T is not linear (Fig. 4c) and the absence of activated behavior rules out the formation of any type of gap as a possible cause of this upturn. The plots of $\ln(\rho)$ versus $T^{-1/4}$ and $T^{-1/2}$ are also not linear (Figs. 4a and b), thereby ruling out an explanation in terms of variable range hopping and Coulomb gap formation mechanisms.⁹ Apparently, there is no $T^{1/2}$ dependence of ρ as well (Fig. 4e), which implies that presently known weak-disorderinduced electron localization ideas discussed by Lee and Ramakrishnan¹⁰ are not adequate to describe the anomalies. Another mechanism that could be advanced is in terms of the formation of magnetic polarons, as proposed for EuSe (Ref. 11), EuB₆ (Ref. 12) and $Tl_2Mn_2O_7$ (Refs. 13-15), but the application of a H is expected to have a pronounced depressing effect on the ρ -upturn resulting in a large negative MR, in contrast to the observation. For the same reason, the s-f exchange model (considering a strong scattering of 5d conduction electrons by the localized $4\tilde{f}$ electrons)¹⁶ proposed to explain the large MR behavior of GdI_2 may not be applicable; additionally, this model assumes ferromagnetic ordering at low temperatures, whereas the present compounds are antiferromagnets; it is not clear whether this model can be modified to explain the features. The fact that ρ behavior in Y and Lu analogues is normal in this regard establishes that the origin of the above ρ anomaly does not lie in the band structure. Thus, there is no straightforward explanation

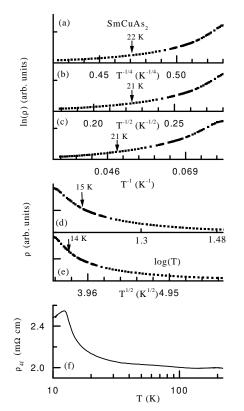


FIG. 4. The electrical resistivity in the temperature range 12.5-31 K plotted in various ways for $SmCuAs_2$ compounds. Fig. (f) shows the 4f contribution in the logarithmic temperature scale in the T range 10-225 K.

We now inspect the ρ behaviour of Pr, Nd and Yb compounds (Fig. 1) along with the χ and C behavior (Figs. 2 and 3). PrCuAs₂ exhibits a distinct feature due to antiferromagnetic ordering at about 4 K, as evidenced by the feature in χ (though the corresponding anomaly in C is not sharp presumably due to low entropy of the crystal-field-split ground state). Nd and Yb compounds are found to order magnetically close to 2.5 and 4.0 K respectively as marked by the features in C and ρ data. It is worth mentioning that, though the T_N values in this series are in general larger than that expected on the basis of de Gennes scaling, this Yb compound turns out to be one of the few Yb compounds exhibiting a high magnetic ordering temperature.¹⁷ This makes this Yb compound interesting in its own right. Following the behaviour in other members of this series described above, one would naively expect that there should be a minimum in the plot of $\rho(T)$ above T_N . However, it is striking to note that no such minimum could be observed for Pr and Yb compounds and the MR is also negligible; in other words, these compounds behave in a normal way in this respect. For the Nd compound, there is a weak upturn below 15 K to the tune of 1% only. We speculate that, at least for

these cases, the origin of this suppression of ρ_{min} may lie in non-negligible degree of 4f-mixing, characteristic not only of Yb, but also of Pr and Nd under favorable circumstances,^{18,19} though there could be other controlling factors.²⁰ In the case of Yb compound, this covalent mixing manifests itself usually as the Kondo effect; the observed behavior of $\rho(\mathbf{T})$ plot above \mathbf{T}_N is typical of Yb-based Kondo lattices²¹ and the temperature (around 130 K) at which ρ starts falling as T is lowered represents the onset of coherent scattering among the Kondo centres.²² The positive sign of MR (see Fig. 1) arising out of destruction of Kondo-coherence by the application of H is consistent with this explanation.²² Therefore, we tend to believe that the Kondo-coherence somehow suppresses the upturn in ρ as T_N is approached. In the case of Pr and Nd compounds, the spatial mixing of 4f (see $Cooper^2$ and Ref. 19), though does not result in the Kondo effect, is apparently effective in depressing ρ_{min} . It is quite well-known¹⁸ that the strength of 4fhybridization decreases progressively as one moves from Ce to Sm and the observation of a similar trend²³ in ρ_{min} supports this interpretation, at least for these cases.

To conclude, we report a new class of rare-earth based intermetallic compounds, RCuAs₂ (R= Sm, Gd, Tb and Dy), with a novel electrical transport behaviour before antiferromagnetic order. The findings imply that the understanding of the electronic transport in the paramagnetic state of relatively simple magnetic metals is far from complete. We propose that the ideas based on weak localisation¹⁰ may have to be extended *incorporating strongly enhanced magnetic critical scattering effects extending over a wide temperature range above* T_o .

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